

## CMOS BCD Rate Multiplier

High-Voltage Types (20-Volt Rating)

■ CD4527B is a low-power 4-bit digital rate multiplier that provides an output-pulse rate which is the clock-input-pulse rate multiplied by 1/10 times the BCD input. For example, when the BCD input is 8, there will be 8 output pulses for every 10 input pulses. This device may be used to perform arithmetic operations (add, subtract, divide, raise to a power), solve algebraic and differential equations, generate natural logarithms and trigonometric functions, A/D and D/A conversion, and frequency division.

For fractional multipliers with more than one digit, CD4527B devices may be cascaded in two different modes: the Add mode and the Multiply mode. (See Figs.12 and 15). In the Add mode,

$$\text{Output Rate} = (\text{Clock Rate}) \left[ \begin{matrix} 0.1 \text{ BCD}_1 + 0.01 \text{ BCD}_2 + \\ 0.001 \text{ BCD}_3 + \dots \end{matrix} \right]$$

In the Multiply mode, the fraction programmed into the first rate multiplier is multiplied by the fraction programmed into the second one,

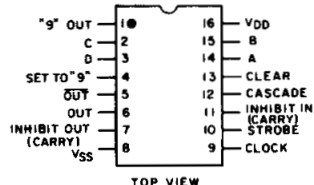
$$\text{e.g. } \frac{9}{10} \times \frac{4}{10} = \frac{36}{100} \text{ or 36 output}$$

pulses for every 100 clock input pulses.

The CD4527B types are supplied in 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (NSR suffix), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

### Applications:

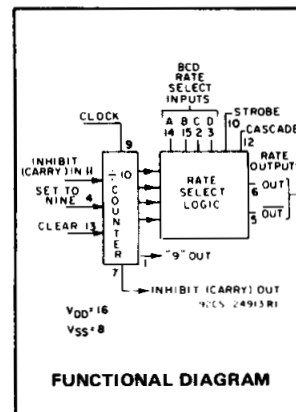
- Numerical control
- Instrumentation
- Digital filtering
- Frequency synthesis



TERMINAL ASSIGNMENT

### Features:

- Cascadable in multiples of 4-bits
- Set to "9" input and "9" detect output
- 100% test for quiescent current at 20 V
- 5-V, 10-V, and 15-V parametric ratings
- Standardized, symmetrical output characteristics
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range) =
  - 1 V at V<sub>DD</sub> = 5 V
  - 2 V at V<sub>DD</sub> = 10 V
  - 2.5 V at V<sub>DD</sub> = 15 V
- Meets all requirements of JEDEC Tentative Standard No. 13B, 'Standard Specifications for Description of 'B' Series CMOS Devices'



### MAXIMUM RATINGS, Absolute-Maximum Values:

#### DC SUPPLY-VOLTAGE RANGE, (V<sub>DD</sub>)

Voltages referenced to V<sub>SS</sub> Terminal) ..... -0.5V to +20V

INPUT VOLTAGE RANGE, ALL INPUTS ..... -0.5V to V<sub>DD</sub> +0.5V

DC INPUT CURRENT, ANY ONE INPUT ..... ±10mA

#### POWER DISSIPATION PER PACKAGE (P<sub>D</sub>):

For T<sub>A</sub> = -55°C to +100°C ..... 500mW

For T<sub>A</sub> = +100°C to +125°C ..... Derate Linearity at 12mW/°C to 200mW

#### DEVICE DISSIPATION PER OUTPUT TRANSISTOR

FOR T<sub>A</sub> = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)..... 100mW

OPERATING-TEMPERATURE RANGE (T<sub>A</sub>) ..... -55°C to +125°C

STORAGE TEMPERATURE RANGE (T<sub>stg</sub>) ..... -65°C to +150°C

#### LEAD TEMPERATURE (DURING SOLDERING):

At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max ..... +265°C

### RECOMMENDED OPERATING CONDITIONS AT T<sub>A</sub> = 25°C, Except as Noted.

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	V <sub>DD</sub> (V)	LIMITS		UNITS		
		Min.	Max.			
Supply Voltage Range (For T <sub>A</sub> = Full Package-Temperature Range)		3	18	V		
Set or Clear Pulse Width, t <sub>W</sub>	5	160	—	ns		
	10	90	—			
	15	60	—			
Clock Pulse Width, t <sub>W</sub>	5	330	—	ns		
	10	170	—			
	15	100	—			
Clock Frequency, f <sub>CL</sub>	5	—	1.2	MHz		
	10	dc	2.5			
	15	—	3.5			
Clock Rise or Fall Time, t <sub>rCL</sub> or t <sub>fCL</sub>	5,10,15	—	15	μs		
	Inhibit In Setup Time, t <sub>SU</sub>	5	100		—	ns
		10	40		—	
15		20	—			
Inhibit In Removal Time, t <sub>REM</sub>	5	240	—	ns		
	10	130	—			
	15	110	—			
Set Removal Time, t <sub>REM</sub>	5	150	—	ns		
	10	80	—			
	15	50	—			
Clear Removal Time, t <sub>REM</sub>	5	60	—	ns		
	10	40	—			
	15	30	—			

# CD4527B Types

## STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V <sub>O</sub> (V)	V <sub>IN</sub> (V)	V <sub>DD</sub> (V)					+25			
				-55	-40	+85	+125	Min.	Typ.	Max.	
Quiescent Device Current, I <sub>DD</sub> Max.	-	0,5	5	5	5	150	150	-	0.04	5	μA
	-	0,10	10	10	10	300	300	-	0.04	10	
	-	0,15	15	20	20	600	600	-	0.04	20	
	-	0,20	20	100	100	3000	3000	-	0.08	100	
Output Low (Sink) Current I <sub>OL</sub> Min.	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-	mA
	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	-	
	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	-	
Output High (Source) Current, I <sub>OH</sub> Min.	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	mA
	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-	
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-	
Output Voltage: Low-Level, V <sub>OL</sub> Max.	-	0,5	5	0.05				-	0	0.05	V
	-	0,10	10	0.05				-	0	0.05	
	-	0,15	15	0.05				-	0	0.05	
Output Voltage: High-Level, V <sub>OH</sub> Min.	-	0,5	5	4.95				4.95	5	-	V
	-	0,10	10	9.95				9.95	10	-	
	-	0,15	15	14.95				14.95	15	-	
Input Low Voltage, V <sub>IL</sub> Max.	0.5, 4.5	-	5	1.5				-	-	1.5	V
	1, 9	-	10	3				-	-	3	
	1.5, 13.5	-	15	4				-	-	4	
Input High Voltage, V <sub>IH</sub> Min.	0.5, 4.5	-	5	3.5				3.5	-	-	V
	1, 9	-	10	7				7	-	-	
	1.5, 13.5	-	15	11				11	-	-	
Input Current I <sub>IN</sub> Max.		0,18	18	±0.1	±0.1	±1	±1	-	±10 <sup>-5</sup>	±0.1	μA

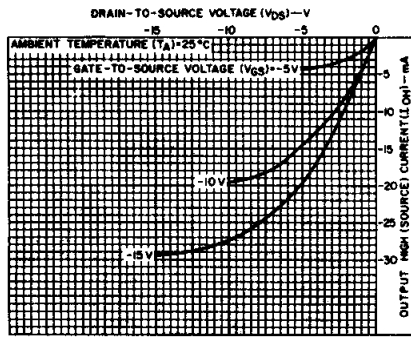


Fig. 3 - Typical output high (source) current characteristics.

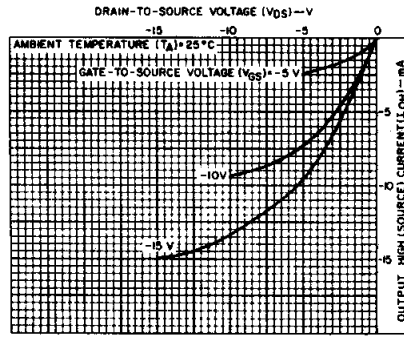


Fig. 4 - Minimum output high (source) current characteristics.

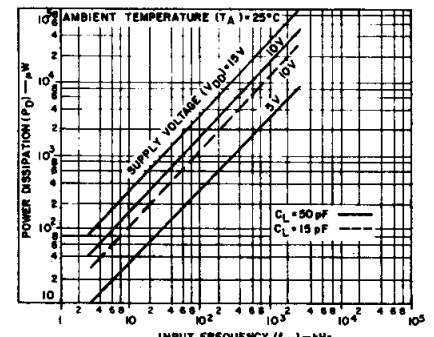


Fig. 5 - Typical dynamic power dissipation as a function of input frequency.

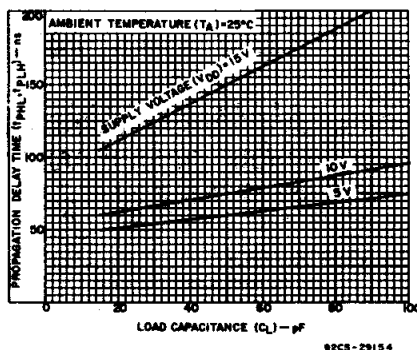


Fig. 6 - Typical propagation delay time as a function of load capacitance (Clock or Strobe to Out).

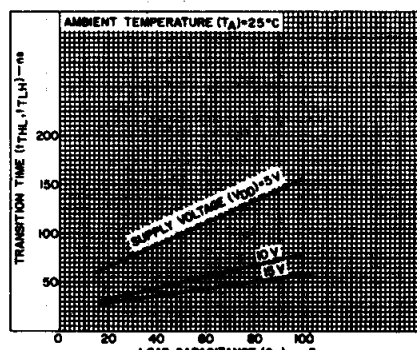


Fig. 7 - Typical transition time as a function of load capacitance.

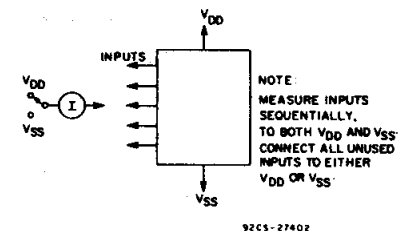


Fig. 8 - Input current test circuit.

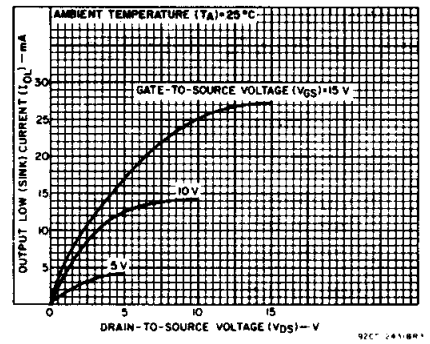


Fig. 1 - Typical output low (sink) current characteristics.

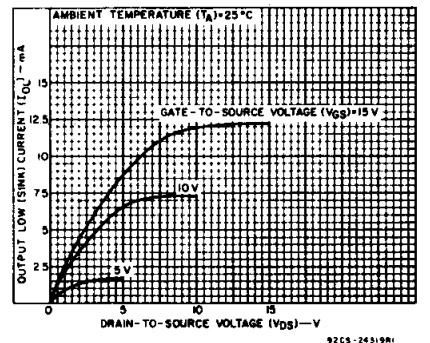


Fig. 2 - Minimum output low (sink) current characteristics.

3  
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# CD4527B Types

**DYNAMIC ELECTRICAL CHARACTERISTICS at T<sub>A</sub> = 25°C:**  
 Input t<sub>r</sub>, t<sub>f</sub> = 20 ns, C<sub>L</sub> = 50 pF, R<sub>L</sub> = 200 kΩ

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS	
		V <sub>DD</sub> (V)	Min.	Typ.		Max.
Propagation Delay Time, t <sub>PHL</sub> , t <sub>PLH</sub> Clock to Out		5	—	110	ns	
		10	—	55		
		15	—	45		
Clock or Strobe to Out		5	—	150	ns	
		10	—	75		
		15	—	60		
Clock to Inhibit Out High Level to Low Level		5	—	320	ns	
		10	—	145		
		15	—	100		
Low Level to High Level		5	—	250	ns	
		10	—	100		
		15	—	75		
Clear to Out		5	—	380	ns	
		10	—	175		
		15	—	130		
Clock to "9" or "15" Out		5	—	300	ns	
		10	—	125		
		15	—	90		
Cascade to Out		5	—	90	ns	
		10	—	45		
		15	—	35		
Inhibit In to Inhibit Out		5	—	130	ns	
		10	—	60		
		15	—	45		
Set to Out		5	—	330	ns	
		10	—	150		
		15	—	110		
Transition Time, t <sub>THL</sub> , t <sub>TLH</sub>		5	—	100	ns	
		10	—	50		
		15	—	40		
Maximum Clock Frequency, f <sub>CL</sub>		5	1.2	2.4	MHz	
		10	2.5	5		
		15	3.5	7		
Minimum Clock Pulse Width, t <sub>w</sub>		5	—	165	ns	
		10	—	85		
		15	—	50		
Clock Rise or Fall Time, t <sub>rCL</sub> , t <sub>fCL</sub>		5	—	15	μs	
		10	—	15		
		15	—	15		
Minimum Set or Clear Pulse Width, t <sub>w</sub>		5	—	80	ns	
		10	—	45		
		15	—	30		
Minimum Inhibit In Setup Time, t <sub>SU</sub>		5	—	50	ns	
		10	—	20		
		15	—	10		
Minimum Inhibit In Removal Time, t <sub>REM</sub>		5	—	120	ns	
		10	—	65		
		15	—	55		
Minimum Set Removal Time, t <sub>REM</sub>		5	—	75	ns	
		10	—	40		
		15	—	25		
Minimum Clear Removal Time, T <sub>REM</sub>		5	—	30	ns	
		10	—	20		
		15	—	15		
Input Capacitance, C <sub>IN</sub>	Any Input		—	5	7.5	pF

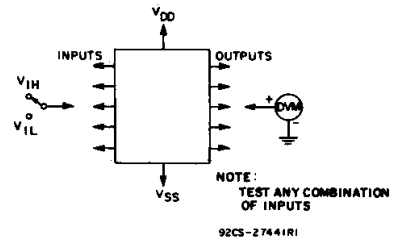


Fig. 9 - Input voltage test circuit.

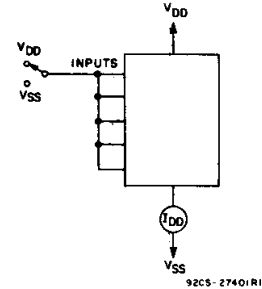


Fig. 10 - Quiescent device current test circuit.

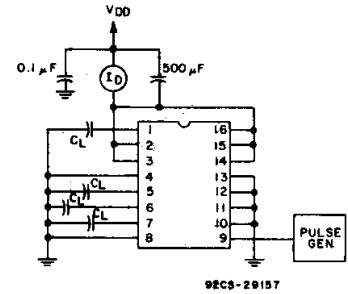


Fig. 11 - Dynamic power dissipation test circuit.

## APPLICATIONS

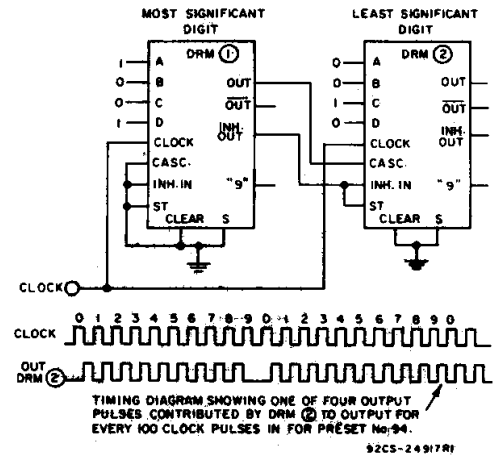


Fig. 12 - Two CD4527B's cascaded in the "Add" mode with a preset number

$$\text{of } 94 \left( \frac{9}{10} + \frac{4}{100} = \frac{94}{100} \right)$$

# CD4527B Types

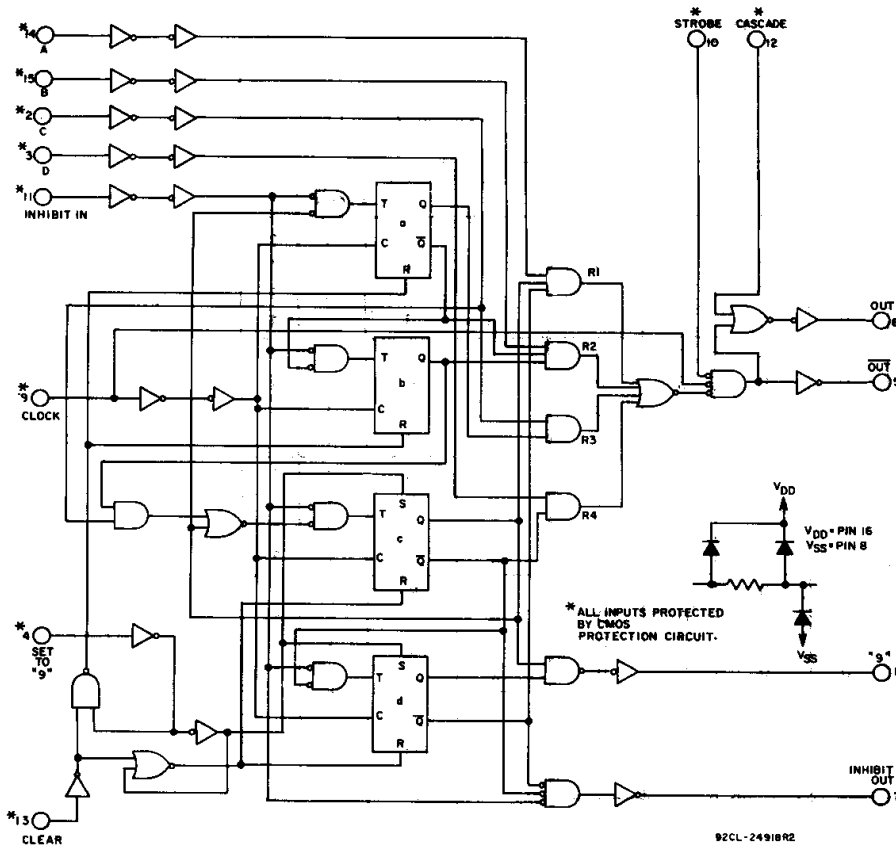


Fig. 13 - Logic diagram.

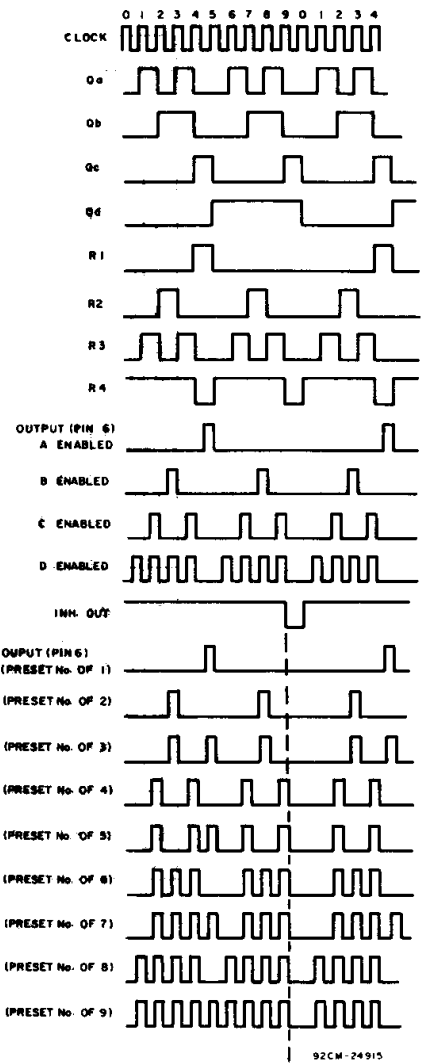
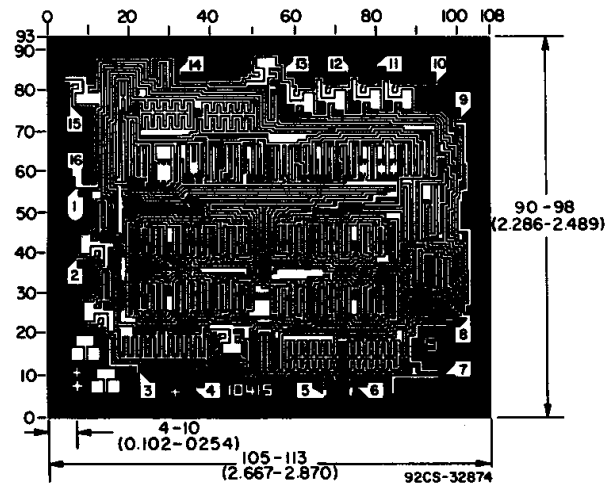


Fig. 14 - Timing diagram (See Logic Diagram).



Dimensions and Pad Layout for CD4527BH

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils ( $10^{-3}$  inch).

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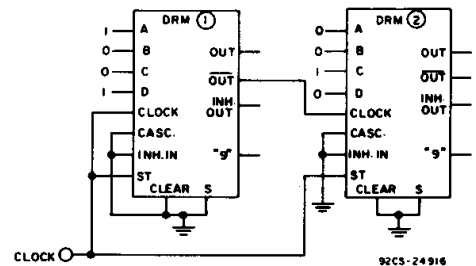


Fig. 15 - Two CD4527B's cascaded in the "Multiply" mode with a preset number

$$\text{of } 36 \left( \frac{9}{10} \times \frac{4}{10} = \frac{36}{100} \right)$$

## CD4527B Types

TRUTH TABLE

INPUTS										OUTPUTS			
Number of Pulses or Input Logic Level (0 = Low; 1 = High; X = Don't Care)										Number of Pulses or Output Logic Level (L = Low; H = High)			
D	C	B	A	CLK	INH IN	STR	CAS	CLR #	SET #	OUT	$\overline{\text{OUT}}$	INH OUT	"9" OUT
0	0	0	0	10	0	0	0	0	0	L	H	1	1
0	0	0	1	10	0	0	0	0	0	1	1	1	1
0	0	1	0	10	0	0	0	0	0	2	2	1	1
0	0	1	1	10	0	0	0	0	0	3	3	1	1
0	1	0	0	10	0	0	0	0	0	4	4	1	1
0	1	0	1	10	0	0	0	0	0	5	5	1	1
0	1	1	0	10	0	0	0	0	0	6	6	1	1
0	1	1	1	10	0	0	0	0	0	7	7	1	1
1	0	0	0	10	0	0	0	0	0	8	8	1	1
1	0	0	1	10	0	0	0	0	0	9	9	1	1
1	0	1	0	10	0	0	0	0	0	8	8	1	1
1	0	1	1	10	0	0	0	0	0	9	9	1	1
1	1	0	0	10	0	0	0	0	0	8	8	1	1
1	1	0	1	10	0	0	0	0	0	9	9	1	1
1	1	1	0	10	0	0	0	0	0	8	8	1	1
1	1	1	1	10	0	0	0	0	0	9	9	1	1
X	X	X	X	10	1	0	0	0	0	†	†	H	†
X	X	X	X	10	0	1	0	0	0	L	H	1	1
X	X	X	X	10	0	0	1	0	0	H	*	1	1
1	X	X	X	10	0	0	0	1	0	10	10	H	L
0	X	X	X	10	0	0	0	1	0	L	H	H	L
X	X	X	X	10	0	0	0	0	1	L	H	L	H

\* Output same as the first 16 lines of this truth table (depending on values of A, B, C, D).

† Depends on internal state of counter.

# Clear and Set Inputs should not be high at the same time; device draws increased quiescent current when in this non-valid state.

**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CD4527BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD4527BNSR	ACTIVE	SO	NS	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD4527BPW	ACTIVE	TSSOP	PW	16	90	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
CD4527BPWR	ACTIVE	TSSOP	PW	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - May not be currently available - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**None:** Not yet available Lead (Pb-Free).

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
  - The 20 pin end lead shoulder width is a vendor option, either half or full width.

# MECHANICAL DATA

NS (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



4040064/F 01/97

- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-153

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DSP	<a href="http://dsp.ti.com">dsp.ti.com</a>	Broadband	<a href="http://www.ti.com/broadband">www.ti.com/broadband</a>
Interface	<a href="http://interface.ti.com">interface.ti.com</a>	Digital Control	<a href="http://www.ti.com/digitalcontrol">www.ti.com/digitalcontrol</a>
Logic	<a href="http://logic.ti.com">logic.ti.com</a>	Military	<a href="http://www.ti.com/military">www.ti.com/military</a>
Power Mgmt	<a href="http://power.ti.com">power.ti.com</a>	Optical Networking	<a href="http://www.ti.com/opticalnetwork">www.ti.com/opticalnetwork</a>
Microcontrollers	<a href="http://microcontroller.ti.com">microcontroller.ti.com</a>	Security	<a href="http://www.ti.com/security">www.ti.com/security</a>
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